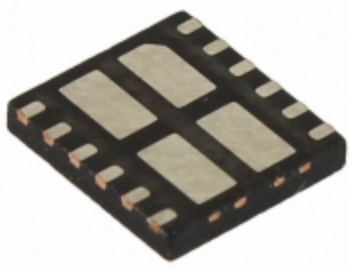

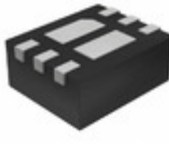
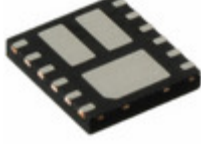
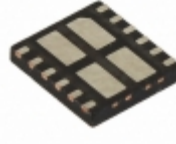
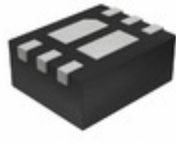

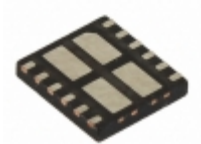
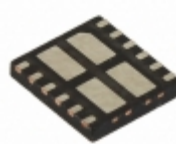
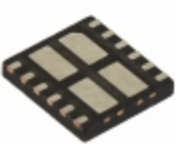
	<h2 style="color: red;">FDMQ8203</h2>	
	<b>Hersteller-Teilenummer:</b>	<a href="#">FDMQ8203</a>
	<b>Hersteller / Marke:</b>	<a href="#">AMI Semiconductor / ON Semiconductor</a>
	<b>Teil der Beschreibung:</b>	MOSFET 2N/2P-CH 100V/80V 12-MLP
<b>Datenblätter:</b>	 <a href="#">FDMQ8203.pdf</a>	
<b>RoHs Status:</b>	Bleifrei / RoHS-konform	
<b>Lagerzustand:</b>	New original, 25580 pcs Stock Available.	
<b>Liefern von:</b>	Hong Kong	
<b>Versandweg:</b>	DHL/Fedex/TNT/UPS/EMS	
<p>Image may be representation. See specs for product details.</p>		

### Spezifikationen

Teilenummer	<a href="#">FDMQ8203</a>
Hersteller	<a href="#">AMI Semiconductor / ON Semiconductor</a>
Beschreibung	MOSFET 2N/2P-CH 100V/80V 12-MLP
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	25580 pcs Stock
Hersteller Standard Vorlaufzeit	6 Weeks
detaillierte Beschreibung	Mosfet Array 2 N and 2 P-Channel (H-Bridge) 100V,
Serie	GreenBridge™ PowerTrench®
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	2.5W
Verpackung / Gehäuse	12-WDFN Exposed Pad
Supplier Device-Gehäuse	12-MLP (5x4.5)
Typ FET	2 N and 2 P-Channel (H-Bridge)
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	100V, 80V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	3.4A, 2.6A
Rds On (Max) @ Id, Vgs	110 mOhm @ 3A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	5nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	210pF @ 50V
Verpackung	Cut Tape (CT)
Basisteilenummer	FDMQ8203
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	FDMQ8203CT

FDMQ8203 ist neu im Original, Suche FDMQ8203 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FDMQ8203 AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FDMQ8203: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>FDMJ1032C</b> Fairchild/ON Semiconductor MOSFET N/P-CH 20V 3.2A/2.5A SC75</p>	 <p><b>FDMQ8403</b> Fairchild/ON Semiconductor MOSFET 4N-CH 100V 3.1A 12-MLP</p>	 <p><b>FDMQ8205</b> Fairchild/ON Semiconductor IC OR CTRLR BRIDGE RECT 12MLP</p>	 <p><b>FDMJ1032C</b> FDK America MOSFET N/P-CH 20V 3.2A/2.5A SC75</p>
 <p><b>FDML7610S</b> AMI Semiconductor / ON Semiconductor MOSFET 2N-CH 30V 12A/17A 8-MLP</p>	 <p><b>FDMQ8205</b> AMI Semiconductor / ON Semiconductor IC OR CTRLR BRIDGE RECT 12MLP</p>	 <p><b>FDMQ8203</b> Fairchild/ON Semiconductor MOSFET 2N/2P-CH 100V/80V 12-MLP</p>	 <p><b>FDMQ8205A</b> AMI Semiconductor / ON Semiconductor GREENBRIDGETM 2 SERIES OF HIGH-E</p>

### heiße Teile

Mehr

 FDMF6707C	 FDMF6707V	 FDMF6707V	 FDMF6708N	 FDMF6708N
 FDMF6717B	 FDMF6820C	 FDMF6820C	 FDMF6821B	 FDMF6821B
 FDMF6823A	 FDMF6823A	 FDMF6823C	 FDMF6823C	 FDMF6840C
 FDMF6840C	 FDMF8700	 FDMF8700	 FDMF8704	 FDMF8704
 FDMF8704TR	 FDMF8704V	 FDMF8704V	 FDMF8705	 FDMF8705
 FDMQ8203	 FDMQ8403	 FDMQ8403	 FDMS015N04B	 FDMS015N04B
 FDMS0300S	 FDMS0300S	 FDMS0302S	 FDMS0302S	 FDMS0306AS
 FDMS0306AS	 FDMS0306S	 FDMS0306S	 FDMS0308AS	 FDMS0308AS
 FDMS0308CS	 FDMS0308CS	 FDMS0308S	 FDMS0309AS	 FDMS0309AS
 FDMS030N06B	 FDMS030N06B	 FDMS0310AS	 FDMS0310AS	 FDMS0310S

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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